

DATA SHEET

TDA5051

Home automation modem

Product specification
Supersedes data of 1997 Mar 11
File under Integrated Circuits, IC11

1997 Sep 19

Home automation modem

TDA5051

FEATURES

- Full digital carrier generation and shaping
- Modulation/demodulation frequency set by clock adjustment, from microcontroller or on-chip oscillator
- High clock rate of 6 bits D/A (Digital-to-Analog) converter for rejection of aliasing components
- Fully integrated output power stage with overload protection
- Automatic gain control at receiver input
- 8-bit A/D and narrow digital filtering
- Digital demodulation delivering baseband data
- Easy compliance with EN50065-1 with simple coupling network
- Few external components for low cost applications
- SO16 plastic package.

APPLICATIONS

- Home appliance control (air conditioning, shutters, lighting, alarms and so on)
- Energy/heating control
- ASK (Amplitude Shift Keying) data transmission using the home power network.

GENERAL DESCRIPTION

The TDA5051 is a modem IC, specifically dedicated to ASK transmission by means of the home power supply network, at 600 or 1200 baud data rate. It operates from a single 5 V supply.

QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V_{DD}	supply voltage		4.75	5.0	5.25	V
$I_{DD(tot)}$	total supply current reception mode transmission mode ($\overline{DATA}_{IN} = 0$) power down mode	$f_{osc} = 8.48 \text{ MHz}$ $Z_L = 30 \Omega$	– – –	28 47 19	38 68 25	mA mA mA
T_{amb}	operating ambient temperature		0	–	70	°C
f_{cr}	carrier frequency	note 1	95	132.5	148.5	kHz
f_{osc}	oscillator frequency		6.08	8.48	9.504	MHz
$V_{o(rms)}$	output carrier signal on CISPR16 load (RMS value)		120	–	122	dB μ V
$V_{i(rms)}$	input signal (RMS value)		66	–	122	dB μ V
THD	total harmonic distortion on CISPR16 load with coupling network		–	–55	–	dB
Z_L	load impedance		1	30	–	Ω
BR	baud rate		–	600	1200	bits/s

Note

1. Frequency range corresponding to the EN50065-1 band. However the modem can operate at any lower oscillator frequency.

ORDERING INFORMATION

TYPE NUMBER	PACKAGE		
	NAME	DESCRIPTION	VERSION
TDA5051T	SO16	plastic small outline package: 16 leads; body width 7.5 mm	SOT162-1

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BLOCK DIAGRAM

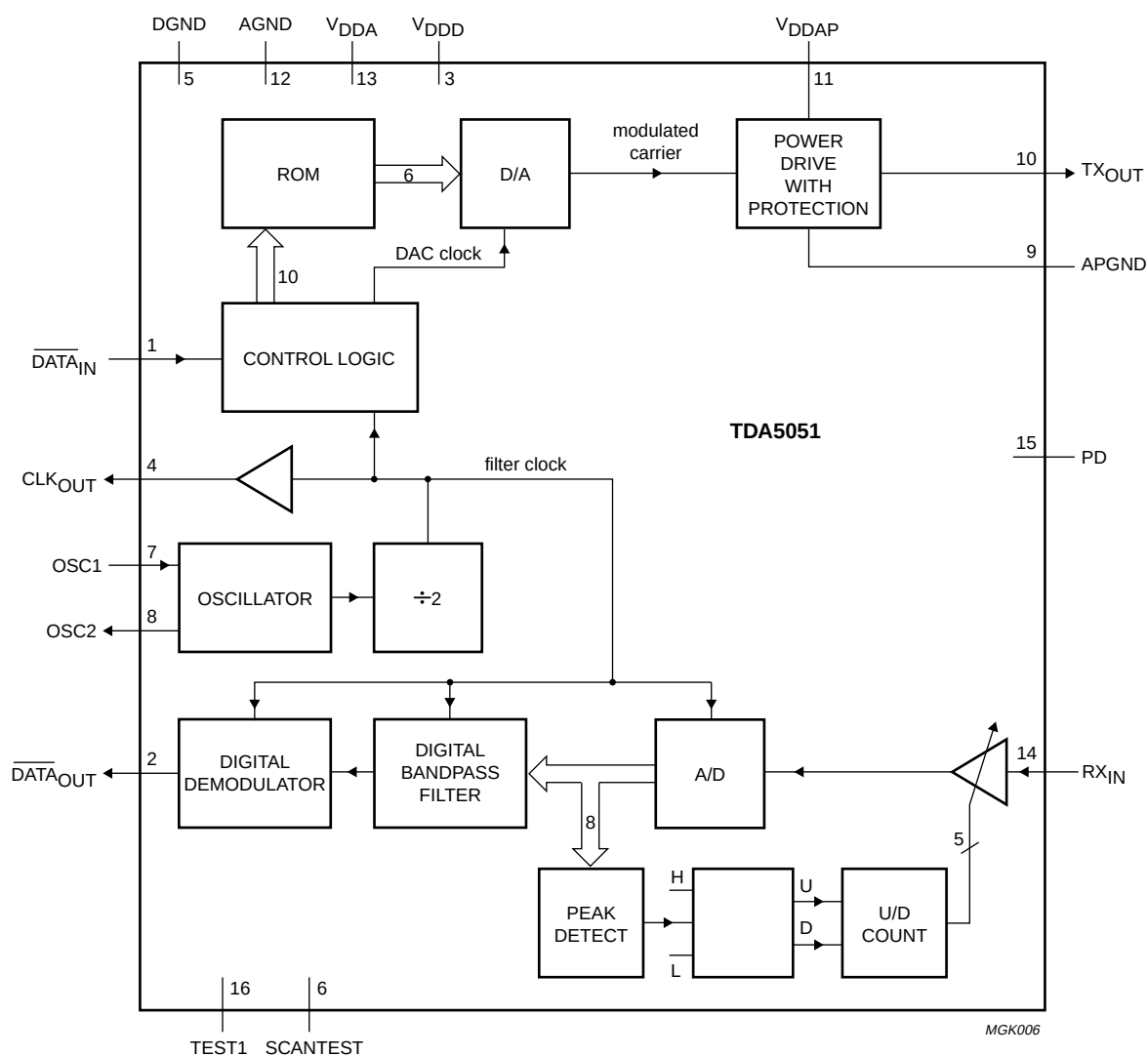


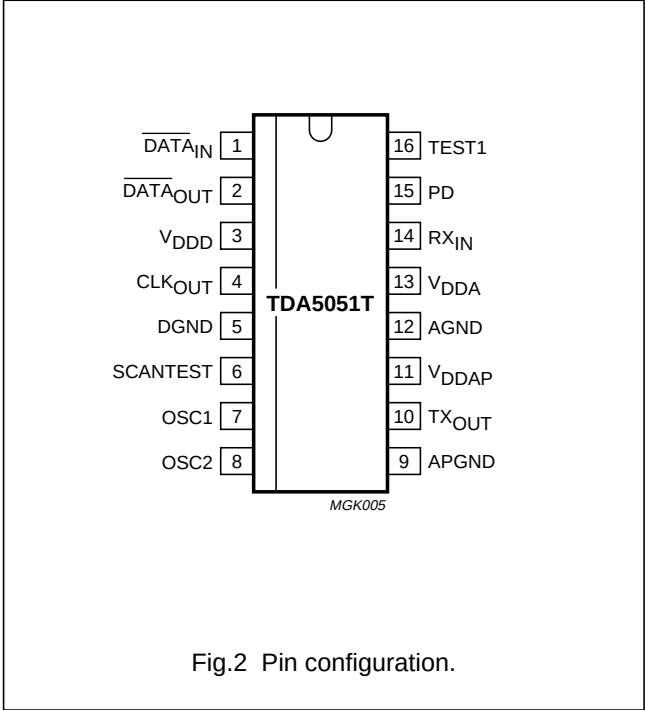
Fig.1 Block diagram.

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PINNING

SYMBOL	PIN	DESCRIPTION
$\overline{\text{DATA}}_{\text{IN}}$	1	digital data input (active LOW)
$\overline{\text{DATA}}_{\text{OUT}}$	2	digital data output (active LOW)
V_{DDD}	3	digital supply voltage
CLK_{OUT}	4	clock output
DGND	5	digital ground
SCANTEST	6	test input (LOW in application)
OSC1	7	oscillator input
OSC2	8	oscillator output
APGND	9	analog ground for power amplifier
TX_{OUT}	10	analog signal output
V_{DDAP}	11	analog supply voltage for power amplifier
AGND	12	analog ground
V_{DDA}	13	analog supply voltage
RX_{IN}	14	analog signal input
PD	15	power-down input (active HIGH)
TEST1	16	test input (HIGH in application)



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FUNCTIONAL DESCRIPTION

Both transmission and reception stages are controlled either by the master clock of the microcontroller, or by the on-chip reference oscillator connected to a crystal. This holds for the accuracy of the transmission carrier and the exact trimming of the digital filter, thus making the performance totally independent of application disturbances such as component spread, temperature, supply drift and so on.

The interface with the power network is made by means of a LC network (see Fig.18). The device includes a power output stage able to feed a 120 dBμV (RMS) signal on a typical 30 Ω load.

To reduce power consumption, the IC is disabled by a power-down input (pin PD): in this mode, the on-chip oscillator remains active and the clock continues to be supplied at pin CLK_{OUT}. For low-power operation in reception mode, this pin can be dynamically controlled by the microcontroller (see Section “Power-down mode”).

When the circuit is connected to an external clock generator (see Fig.6), the clock signal must be applied at pin OSC1 (pin 7); OSC2 (pin 8) must be left open. Use of the on-chip clock circuitry is shown in Fig.7.

All logic inputs and outputs are compatible with TTL/CMOS levels, providing an easy connection to a standard microcontroller I/O port.

The digital part of the IC is fully scan-testable. Two digital inputs, SCANTEST and TEST1, are used for production test: these pins must be left open in functional mode (correct levels are internally defined by pull-up/down resistors).

Transmission mode

The carrier frequency is generated by the scanning of a ROM memory under the control of the microcontroller clock or the reference frequency provided by the on-chip oscillator, thus providing strict stability with respect to environmental conditions. High frequency clocking rejects the aliasing components to such an extent that they are filtered by the coupling LC network and do not cause any significant disturbance. The data modulation is applied through pin DATA_{IN} and smoothly applied by specific digital circuitry to the carrier (shaping). Harmonic components are limited in this process, thus avoiding unacceptable disturbance of the transmission channel (according to CISPR16 and EN50065-1 recommendations). A –55 dB total harmonic distortion is reached when using the typical LC coupling network (or an equivalent filter).

The D/A converter and the power stage are set in order to provide a maximum signal level of 122 dBμV (RMS) at the output.

The output of the power stage (TX_{OUT}) **always** has to be connected to a decoupling capacitor, because of a DC level of 0.5V_{DD} at this pin, present even when the device is not transmitting. This pin also has to be **protected against overvoltage and negative transient signals**. The DC level of TX_{OUT} can be used to bias an unipolar transient suppressor, as shown in the application diagram (see Fig.18).

Direct connection to the mains is done through a LC network for low-cost applications. However, a HF signal transformer could be used when power-line insulation has to be performed.

CAUTION

In transmission mode, the receiving part of the circuit is **not disabled** and the detection of the transmitted signal is normally performed. In this mode, the gain chosen before the beginning of the transmission is stored, and the **AGC is internally set to –6 dB** as long as DATA_{IN} is LOW. Then, the old gain setting is **automatically restored**.

Receiving mode

The input signal received by the modem is applied to a wide range input amplifier with Automatic Gain Control (AGC) (–6 to +30 dB). This is basically for noise performance improvement and signal level adjustment that ensures a maximum sensitivity of the A/D converter. Then an 8 bit A/D conversion is performed, followed by digital bandpass filtering, in order to meet the CISPR normalization and to comply with some additional limitations encountered in current applications. After digital demodulation, the baseband data signal is made available after pulse shaping.

The signal pin (RX_{IN}) is a high-impedance input, which has to be protected and DC decoupled for the same reasons as with pin TX_{OUT}. The high sensitivity (66 dBμV) of this input requires an efficient 50 Hz rejection filter (realized by the LC coupling network) also used as an anti-aliasing filter for the internal digital processing (see Fig.18).

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Data format**TRANSMISSION MODE**

The data input ($\overline{\text{DATA}}_{\text{IN}}$) is active LOW: this means that a burst is generated on the line (pin TX_{OUT}) when pin $\overline{\text{DATA}}_{\text{IN}}$ is LOW.

Pin TX_{OUT} is in high-impedance state as long as the device is not transmitting. Successive logic 1s are treated in a NRZ mode (see pulse shape description in Figs 8 and 9).

RECEIVING MODE

The data output (pin $\overline{\text{DATA}}_{\text{OUT}}$) is active LOW; this means that the data output is LOW when a burst is received. Pin $\overline{\text{DATA}}_{\text{OUT}}$ remains LOW as long as a burst is received.

Power-down mode

Power-down input (pin PD) is active HIGH; this means that the power consumption is minimal when pin PD is HIGH. All functions, except clock generation, are disabled then.

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
V_{DD}	supply voltage	4.5	5.5	V
f_{osc}	oscillator frequency	–	12	MHz
T_{stg}	storage temperature	–50	+150	°C
T_{amb}	operating ambient temperature	–10	+80	°C
T_{j}	junction temperature	–	125	°C

HANDLING

Inputs and outputs are protected against electrostatic discharge in normal handling. However, to be totally safe, it is desirable to take normal precautions appropriate to handling MOS devices.

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CHARACTERISTICS

$V_{DD} = V_{DDA} = 5\text{ V} \pm 5\%$; $T_{\text{amb}} = 0\text{ to }70\text{ }^{\circ}\text{C}$; V_{DD} connected to V_{DDA} ; DGND connected to AGND.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Supply						
V_{DD}	supply voltage		4.75	5	5.25	V
$I_{DD(RX/TX)(\text{tot})}$	total analog + digital supply current; TX or RX mode	$V_{DD} = 5\text{ V} \pm 5\%$	–	28	38	mA
$I_{DD(PD)(\text{tot})}$	total analog + digital supply current; power-down mode	$V_{DD} = 5\text{ V} \pm 5\%$; PD = HIGH	–	19	25	mA
$I_{DD(PAMP)}$	power amplifier supply current in transmission mode	$V_{DD} = 5\text{ V} \pm 5\%$; $Z_L = 30\text{ }\Omega$; $\overline{\text{DATA}}_{\text{IN}} = \text{LOW}$	–	19	30	mA
$I_{DD(PAMP)(\text{max})}$	maximum power amplifier supply current in transmission mode	$V_{DD} = 5\text{ V} \pm 5\%$; $Z_L = 1\text{ }\Omega$; $\overline{\text{DATA}}_{\text{IN}} = \text{LOW}$	–	76	–	mA
$\overline{\text{DATA}}_{\text{IN}}$ input, PD input: $\overline{\text{DATA}}_{\text{OUT}}$ output, CLK_{OUT} output						
V_{IH}	HIGH-level input voltage		$0.2V_{DD} + 0.9$	–	$V_{DD} + 0.5$	V
V_{IL}	LOW-level input voltage		–0.5	–	$0.2V_{DD} - 0.1$	V
V_{OH}	HIGH-level output voltage	$I_{OH} = -1.6\text{ mA}$	2.4	–	–	V
V_{OL}	LOW-level output voltage	$I_{OL} = 1.6\text{ mA}$	–	–	0.45	V
OSC1 input and OSC2 output (OSC2 only used for driving external quartz crystal; must be left open when using an external clock generator)						
V_{IH}	HIGH-level input voltage		$0.7V_{DD}$	–	$V_{DD} + 0.5$	V
V_{IL}	LOW-level input voltage		–0.5	–	$0.2V_{DD} - 0.1$	V
V_{OH}	HIGH-level output voltage	$I_{OH} = -1.6\text{ mA}$	2.4	–	–	V
V_{OL}	LOW-level output voltage	$I_{OL} = 1.6\text{ mA}$	–	–	0.45	V
Clock						
f_{osc}	oscillator frequency		6.080	–	9.504	MHz
$\frac{f_{\text{osc}}}{f_{\text{cr}}}$	ratio between oscillator and carrier frequency		–	64	–	
$\frac{f_{\text{osc}}}{f_{\text{CLKOUT}}}$	ratio between oscillator and clock output frequency		–	2	–	

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SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Transmission mode						
f_{cr}	carrier frequency	$f_{osc} = 8.48 \text{ MHz}$	–	132.5	–	kHz
t_{su}	set-up time of the shaped burst	$f_{osc} = 8.48 \text{ MHz}$; see Fig.8	–	170	–	μs
t_h	hold time of the shaped burst	$f_{osc} = 8.48 \text{ MHz}$; see Fig.8	–	170	–	μs
$t_{W(DI)(min)}$	minimum pulse width of $\overline{\text{DATA}}_{IN}$ signal	$f_{osc} = 8.48 \text{ MHz}$; see Fig.8	–	190	–	μs
$V_{o(rms)}$	output carrier signal (RMS value)	$Z_L = \text{CISPR16}$ $\overline{\text{DATA}}_{IN} = \text{LOW}$	120	–	122	$\text{dB}\mu\text{V}$
$I_{o(max)}$	power amplifier maximum output current (peak value)	$Z_L = 1 \Omega$; $\overline{\text{DATA}}_{IN} = \text{LOW}$	–	160	–	mA
Z_o	output impedance of the power amplifier		–	5	–	Ω
V_O	output DC level at TX_{OUT}		–	2.5	–	V
THD	total harmonic distortion on CISPR16 load with the coupling network (measured on the first ten harmonics)	$V_{o(rms)} = 121 \text{ dB}\mu\text{V}$ on CISPR16 load; $f_{osc} = 8.48 \text{ MHz}$; $\overline{\text{DATA}}_{IN} = \text{LOW}$ (no modulation); see Figs 3 and 16	–	–55	–	dB
B_{-20dB}	bandwidth of the shaped output signal (at –20 dB) on CISPR16 load with the coupling network	$V_{o(rms)} = 121 \text{ dB}\mu\text{V}$ on CISPR16 load; $f_{osc} = 8.48 \text{ MHz}$; $\overline{\text{DATA}}_{IN} = 300 \text{ Hz}$; duty factor = 50%; see Fig.4	–	3000	–	Hz
Reception mode						
$V_{i(rms)}$	analog input signal (RMS value)		68	–	122	$\text{dB}\mu\text{V}$
V_I	DC level at pin RX_{IN}		–	2.5	–	V
Z_i	RX_{IN} input impedance		–	50	–	$\text{k}\Omega$
R_{AGC}	automatic gain control range		–	36	–	dB
$t_{c(AGC)}$	automatic gain control time constant	$f_{osc} = 8.48 \text{ MHz}$; see Fig.5	–	296	–	μs
$t_{d(dem)(su)}$	demodulation delay set-up time	$f_{osc} = 8.48 \text{ MHz}$; see Fig.15	–	410	460	μs
$t_{d(dem)(h)}$	demodulation delay hold time	$f_{osc} = 8.48 \text{ MHz}$; see Fig.15	–	330	380	μs
B_{det}	detection bandwidth	$f_{osc} = 8.48 \text{ MHz}$	–	3	–	kHz

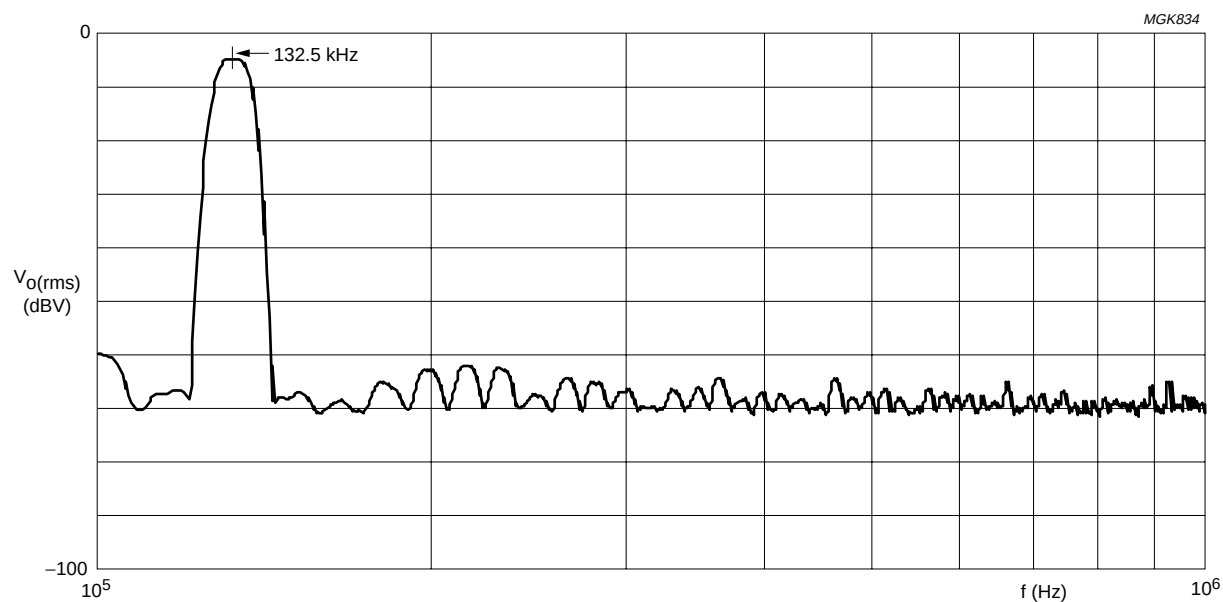
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SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
BER	bit error rate	$f_{osc} = 8.48 \text{ MHz}$; 600 baud; S/N = 35 dB; signal 76 dB μ V; see Fig.17	—	1	—	1×10^{-4}
Power-up timing						
$t_{d(pu)(TX)}$	delay between power-up and $\overline{DATA}_{IN}$ in transmission mode	XTAL = 8.48 MHz; C1 = C2 = 27 pF; $R_p = 2.2 \text{ M}\Omega$; see Fig.10	—	1	—	μ s
$t_{d(pu)(RX)}$	delay between power-up and $\overline{DATA}_{OUT}$ in reception mode	XTAL = 8.48 MHz; C1 = C2 = 27 pF; $R_p = 2.2 \text{ M}\Omega$; $f_{RXIN} = 132.5 \text{ kHz}$; 120 dB μ V sinewave; see Fig.11	—	1	—	μ s
Power-down timing						
$t_{d(pd)(TX)}$	delay between PD = 0 and $\overline{DATA}_{IN}$ in transmission mode	$f_{osc} = 8.48 \text{ MHz}$; see Fig.12	—	10	—	μ s
$t_{d(pd)(RX)}$	delay between PD = 0 and $\overline{DATA}_{OUT}$ in reception mode	$f_{osc} = 8.48 \text{ MHz}$; $f_{RXIN} = 132.5 \text{ kHz}$; 120 dB μ V sinewave; see Fig.13	—	500	—	μ s
$t_{active(min)}$	minimum active time with T = 10 ms power-down period in reception mode	$f_{osc} = 8.48 \text{ MHz}$; $f_{RXIN} = 132.5 \text{ kHz}$; 120 dB μ V sinewave; see Fig.14	—	1	—	μ s

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Resolution bandwidth = 9 kHz; top: 0 dBV (RMS) = 120 dB μ V (RMS); marker at -5 dBV (RMS) = 115 dB μ V (RMS); the CISPR16 network provides an attenuation of 6 dB, so the signal amplitude is 121 dB μ V (RMS).

Fig.3 Carrier spectrum.

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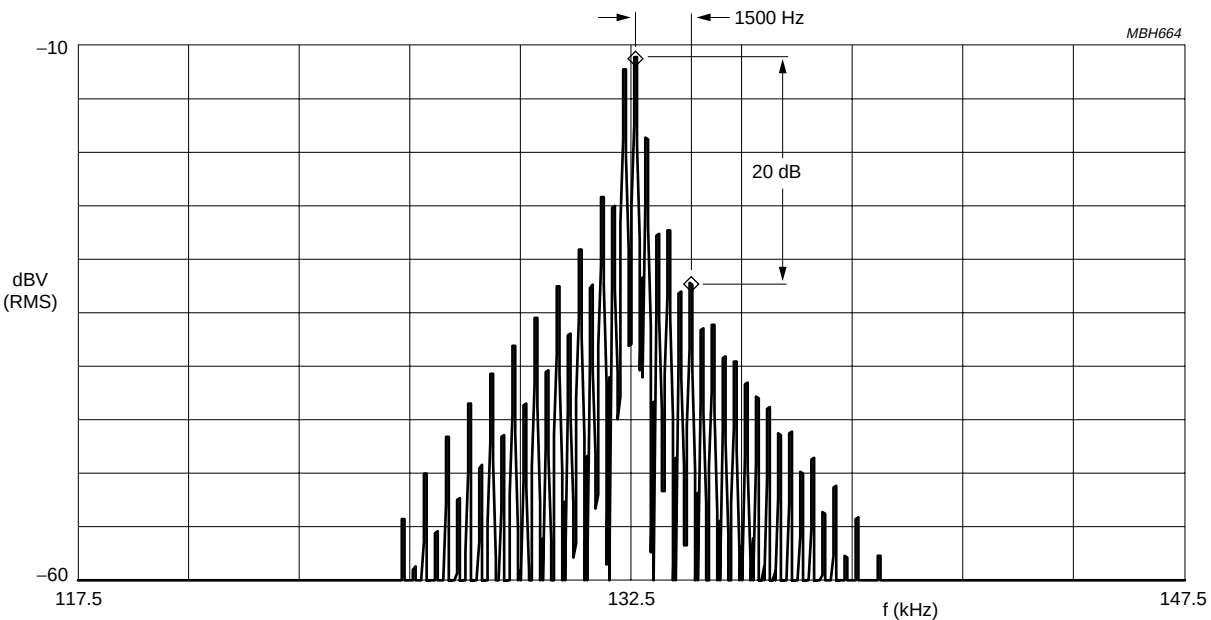


Fig.4 Shaped signal spectrum.

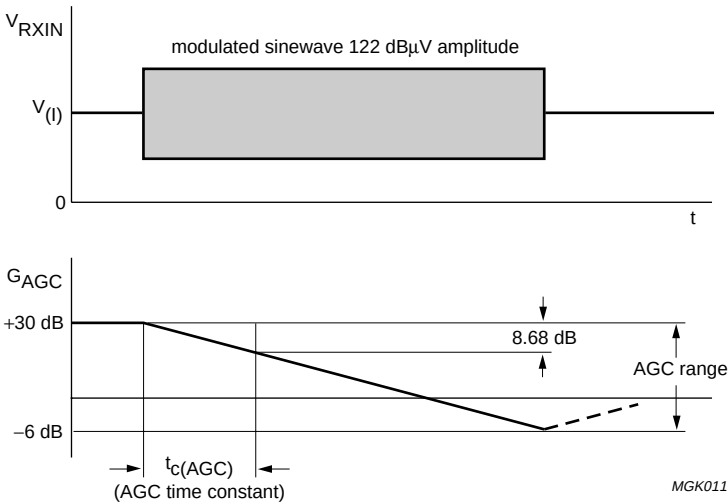


Fig.5 AGC time constant definition (not to scale).

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TIMING

Configurations for clock

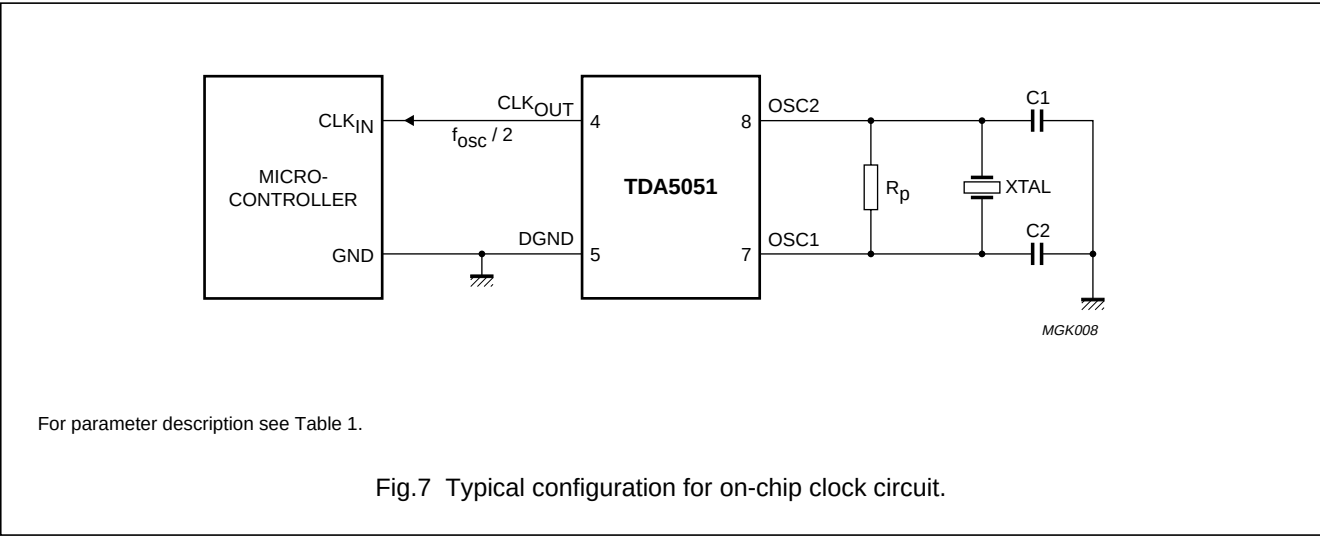
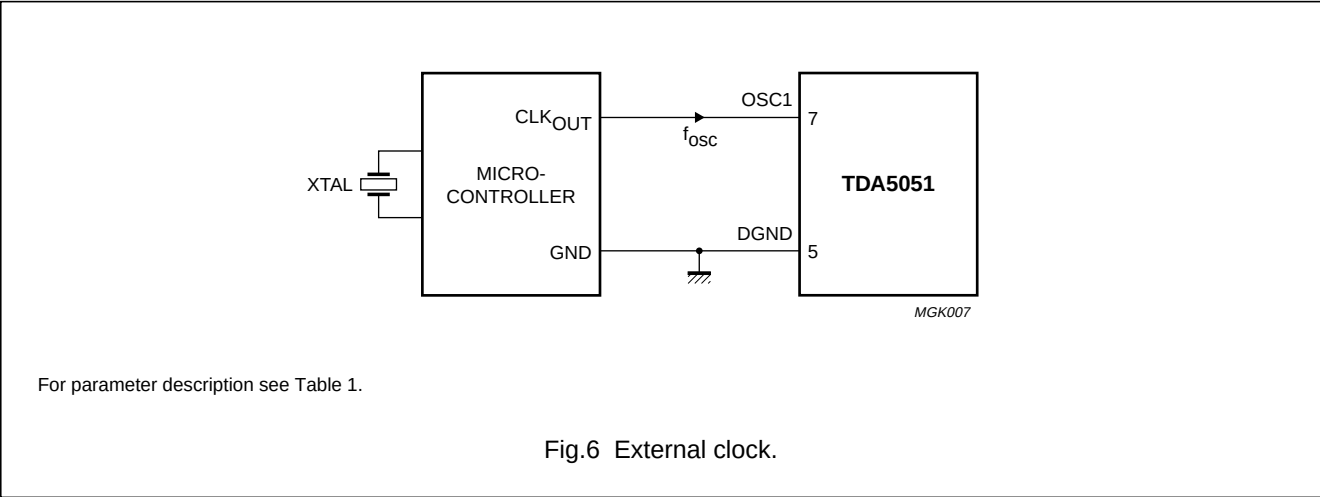


Table 1 Clock oscillator parameters

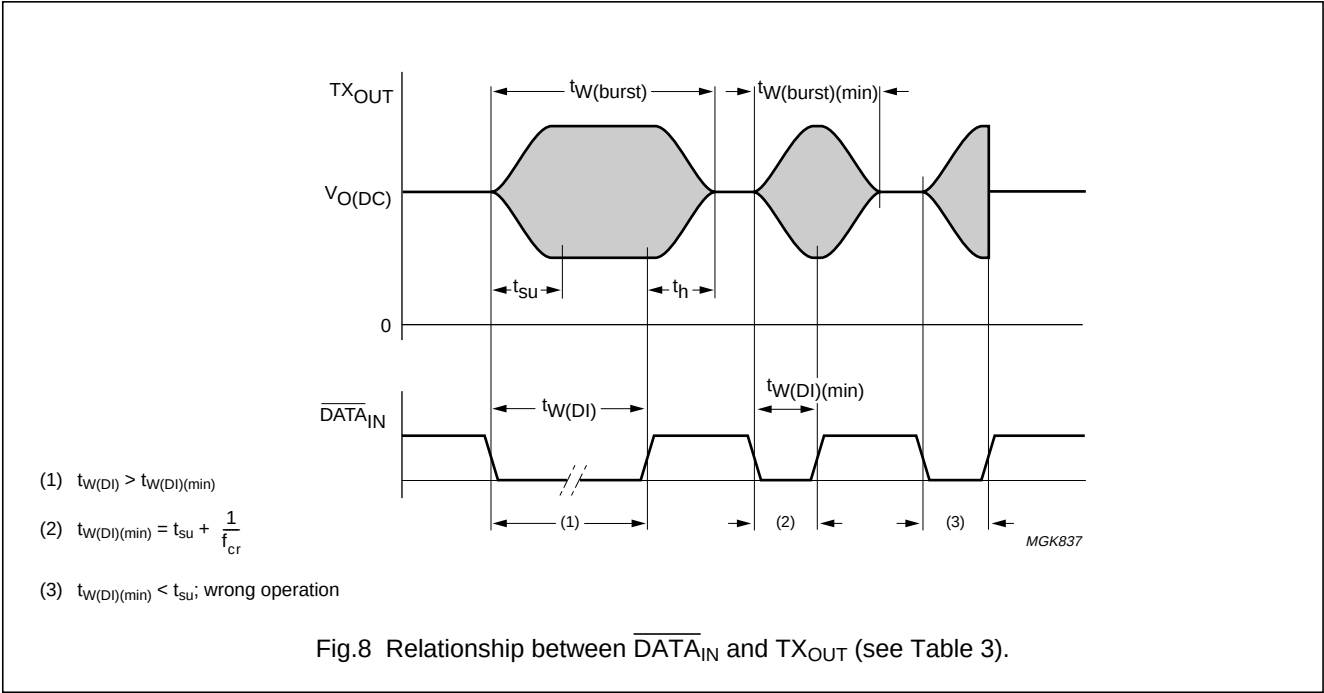
f_{osc} OSCILLATOR FREQUENCY	f_{cr} CARRIER FREQUENCY	$\frac{1}{2}f_{osc}$ CLOCK OUTPUT FREQUENCY	EXTERNAL COMPONENTS
6.080 to 9.504 MHz	95 to 148.5 kHz	3.040 to 4.752 MHz	$C1 = C2 = 27$ to 47 pF; $R_p = 2.2$ to 4.7 M Ω ; XTAL = standard quartz crystal

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Table 2 Calculation of parameters depending of the clock frequency

SYMBOL	PARAMETER	CONDITIONS	UNIT
f _{osc}	oscillator frequency	with on-chip oscillator: frequency of the crystal quartz; with external clock: frequency of the signal applied at OSC1	Hz
f _{CLKOUT}	clock output frequency	$\frac{1}{2}f_{osc}$	Hz
f _{cr}	carrier frequency/digital filter tuning frequency	$\frac{1}{64}f_{osc}$	Hz
t _{su}	set-up time of the shaped burst	$\frac{23}{f_{cr}}$ or $\frac{1472}{f_{osc}}$	s
t _h	hold time of the shaped burst	$\frac{23}{f_{cr}}$ or $\frac{1472}{f_{osc}}$	s
t _{W(DI)(min)}	minimum pulse width of $\overline{DATA}_{IN}$ signal	$t_{su} + \frac{1}{f_{cr}}$	s
t _{W(burst)(min)}	minimum burst time of V _{O(DC)} signal	t _{W(DI)(min)} + t _h	s
t _{c(AGC)}	AGC time constant	$\frac{2514}{f_{osc}}$	s
t _{su(demod)}	demodulation set-up time	$\frac{3700}{f_{osc}}$ (≈max.)	s
t _{h(demod)}	demodulation hold time	$\frac{3050}{f_{osc}}$ (≈max.)	s



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Table 3 Relationship between $\overline{\text{DATA}}_{\text{IN}}$ and TX_{OUT}

PD	$\overline{\text{DATA}}_{\text{IN}}$	TX_{OUT}
1	X ⁽¹⁾	high impedance
0	1	high impedance (after t_h)
0	0	active with DC offset

Note

1. X = don't care.

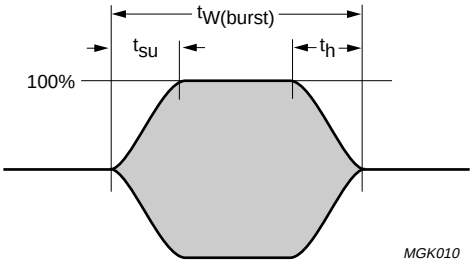
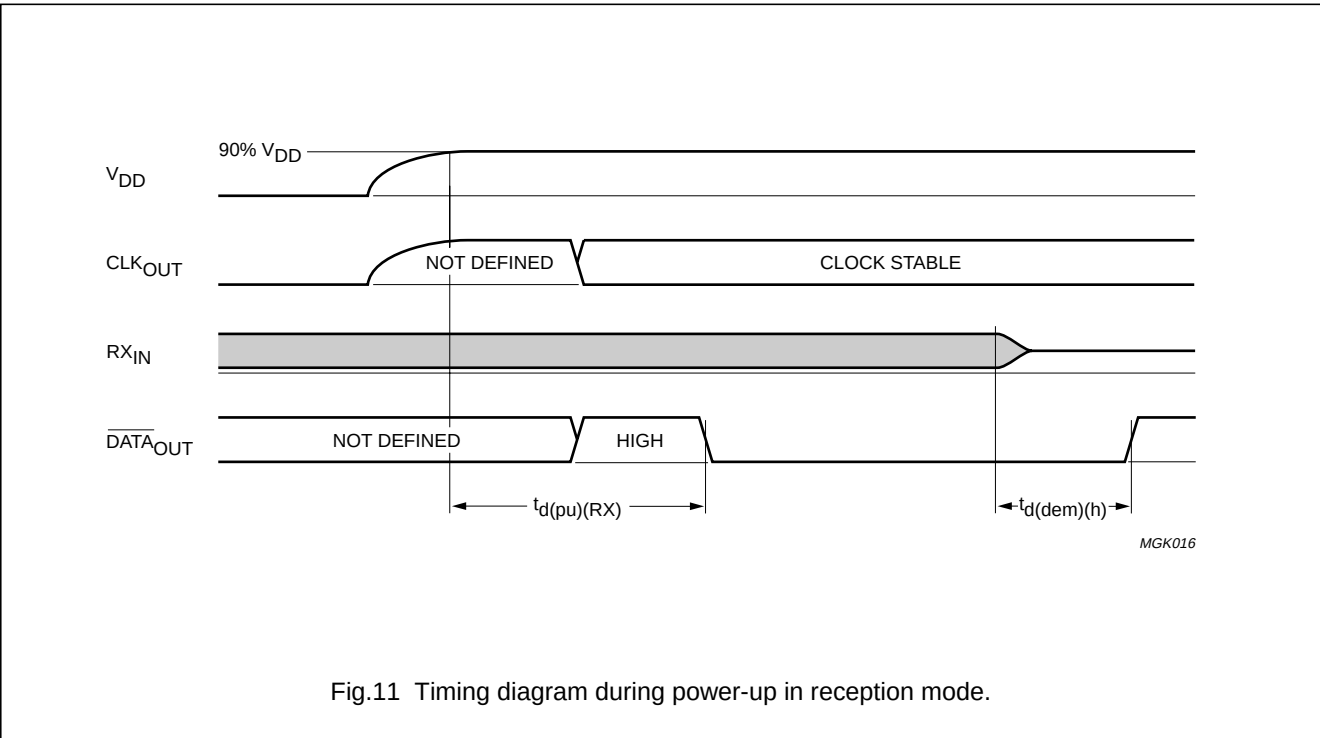
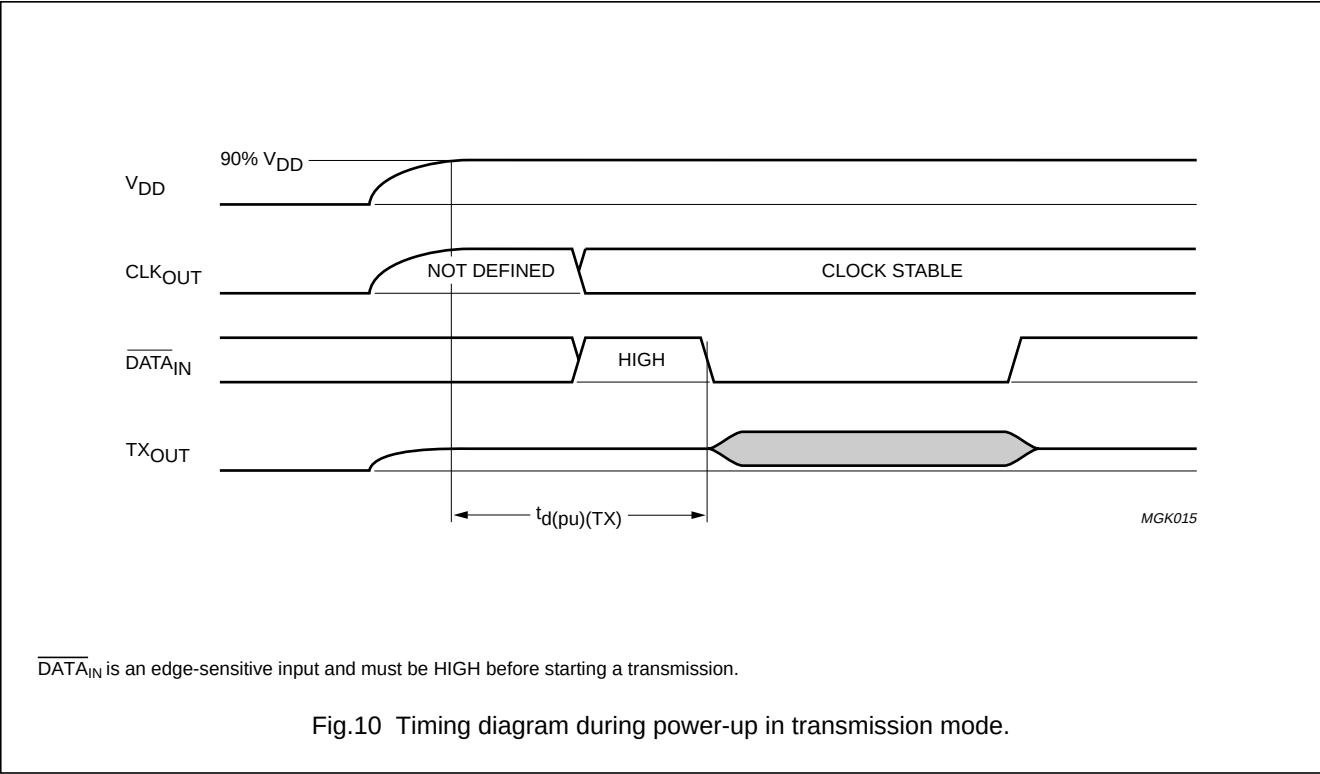


Fig.9 Pulse shape characteristics.

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Timing diagrams



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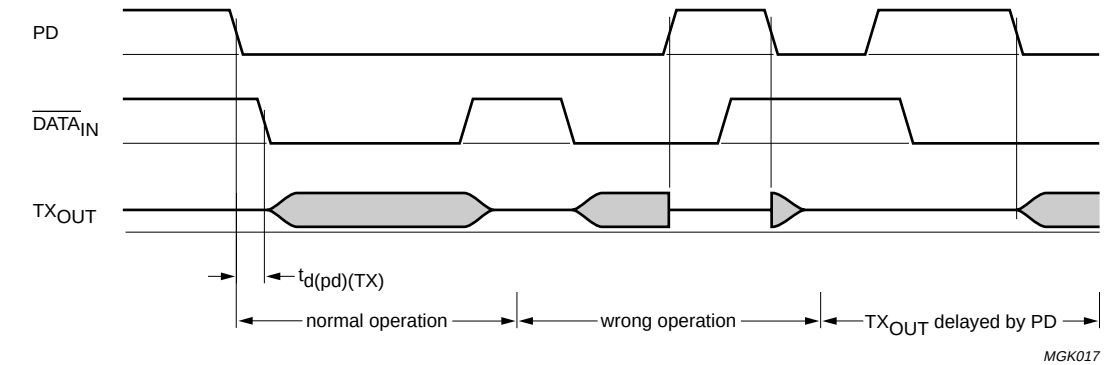


Fig.12 Power-down sequence in transmission mode.

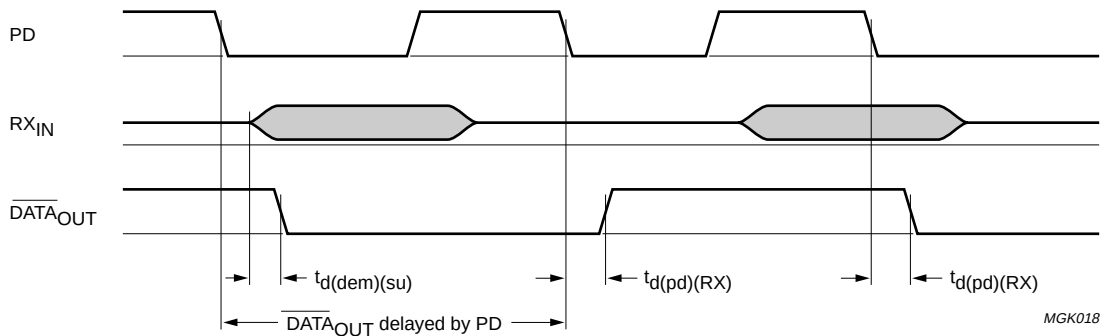


Fig.13 Power-down sequence in reception mode.

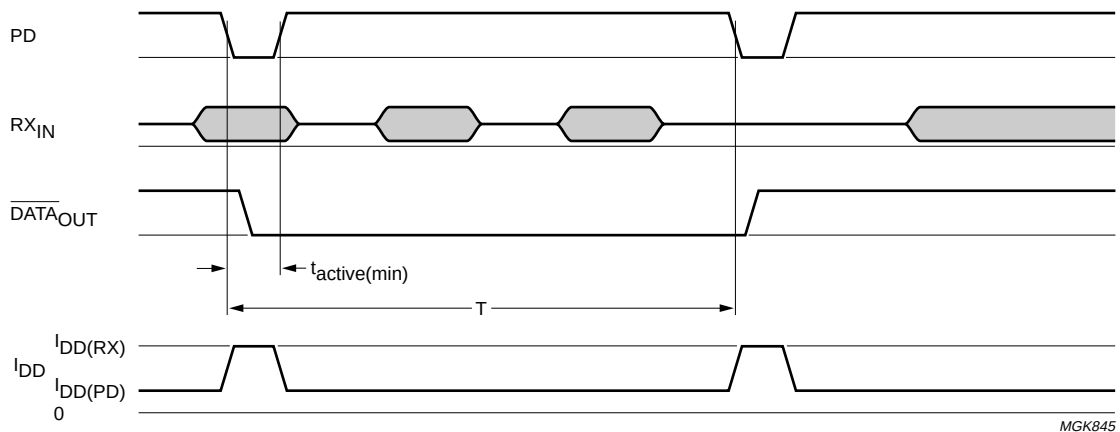


Fig.14 Power saving by dynamic control of power-down.

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TEST INFORMATION

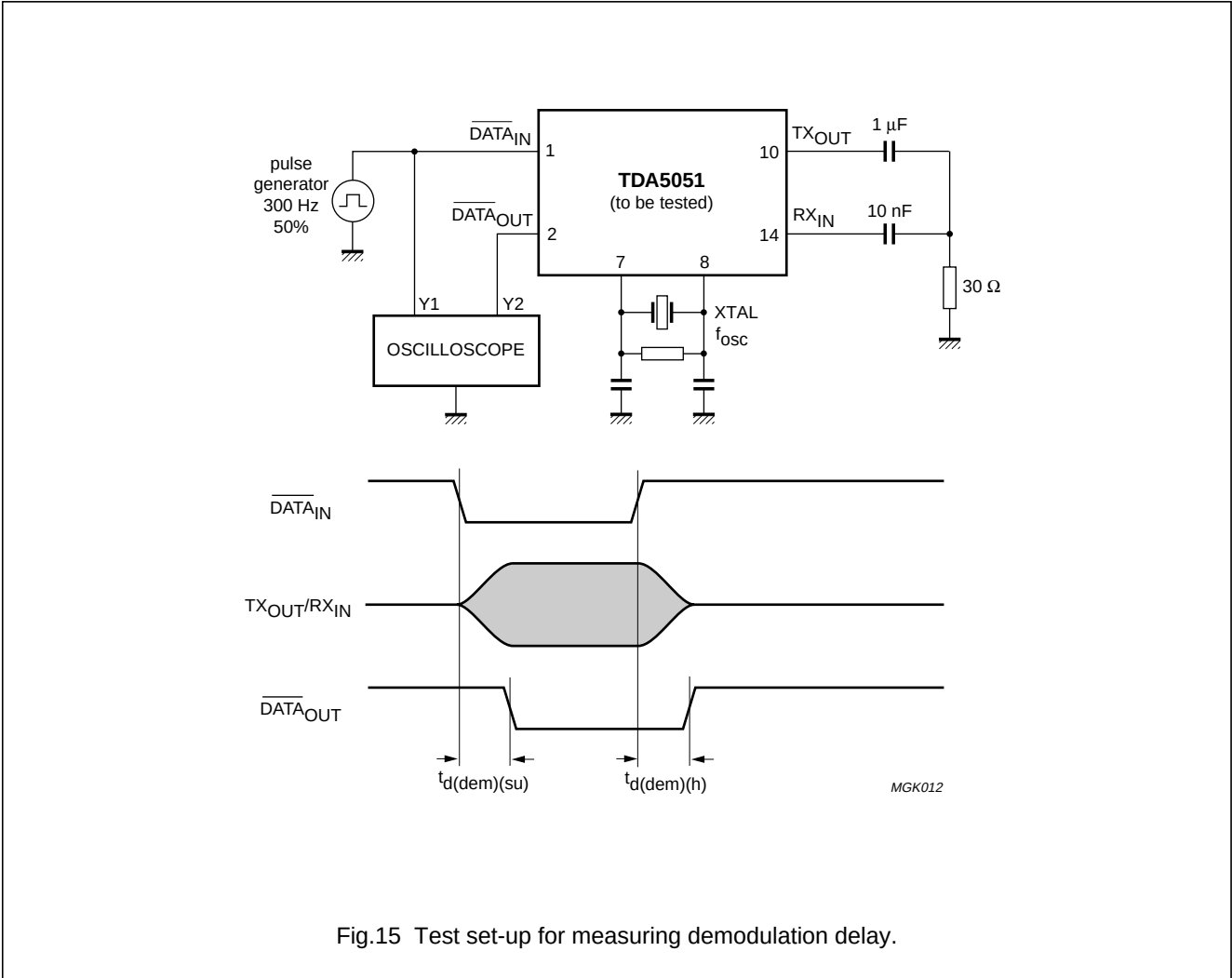
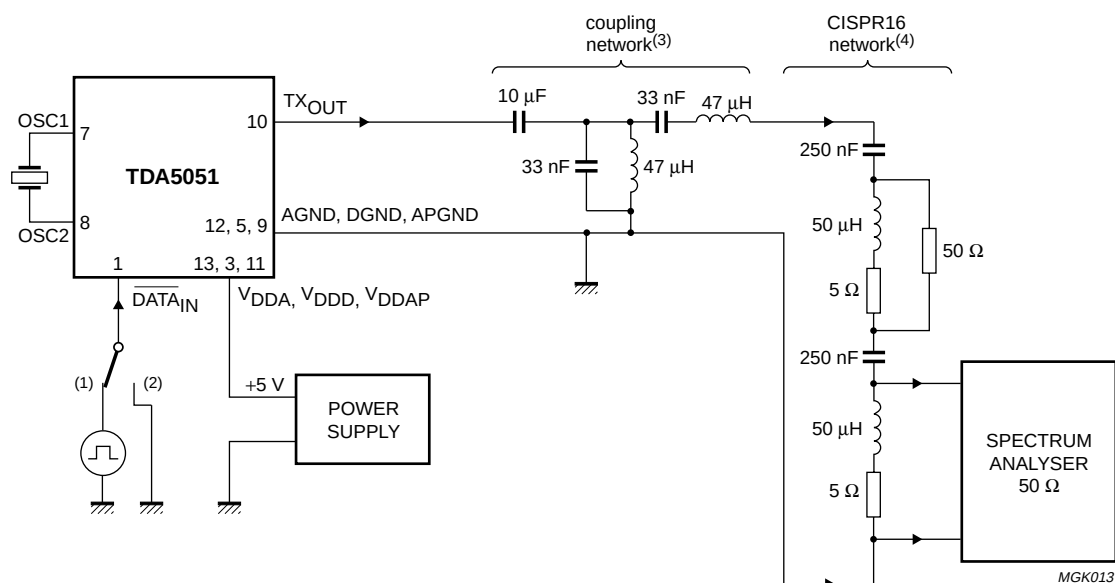


Fig.15 Test set-up for measuring demodulation delay.

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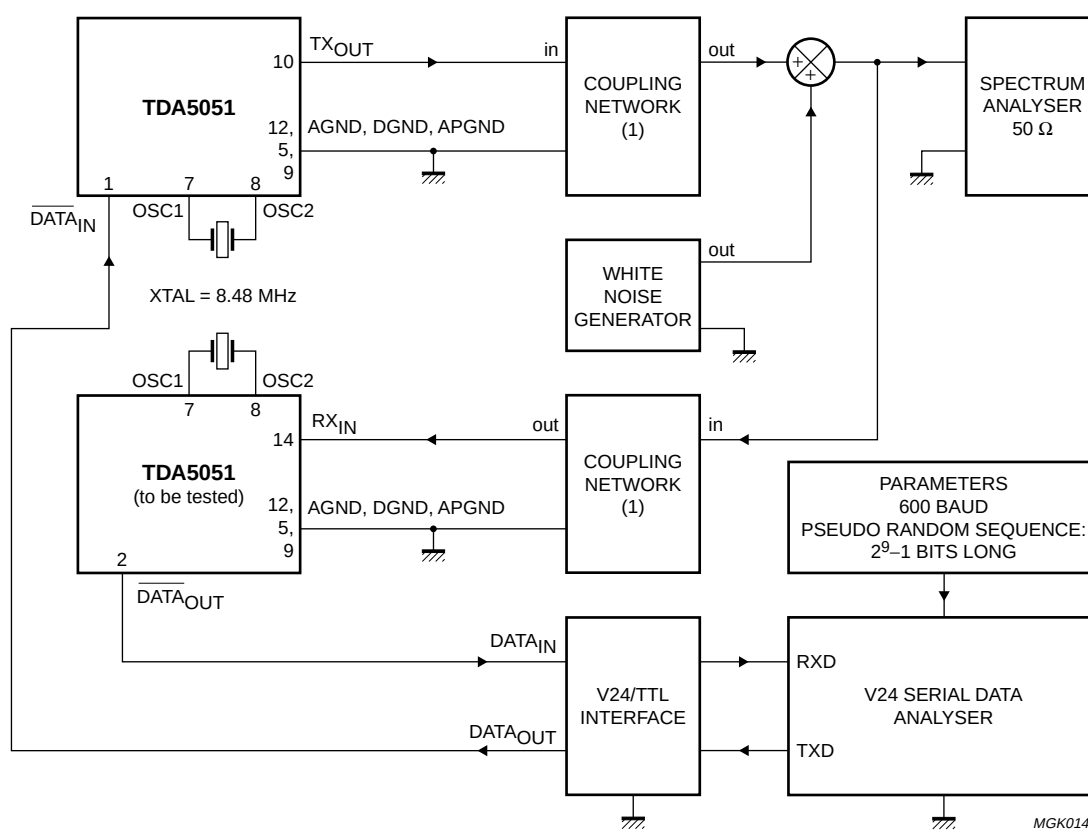


- (1) Square wave TTL signal 300 Hz, duty factor = 50% for measuring signal bandwidth (see spectrum Fig.3).
- (2) $\overline{\text{DATA}}_{\text{IN}} = \text{LOW}$ for measuring total harmonic distortion (see spectrum Fig.3).
- (3) Tuned for $f_{\text{cr}} = 132.5 \text{ kHz}$.
- (4) The CISPR16 network provides a -6 dB attenuation.

Fig.16 Test set-up for measuring THD and bandwidth of the TX_{OUT} signal.

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(1) See Fig.16.

Fig.17 Test set-up for measuring bit error rate (BER).

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APPLICATION INFORMATION

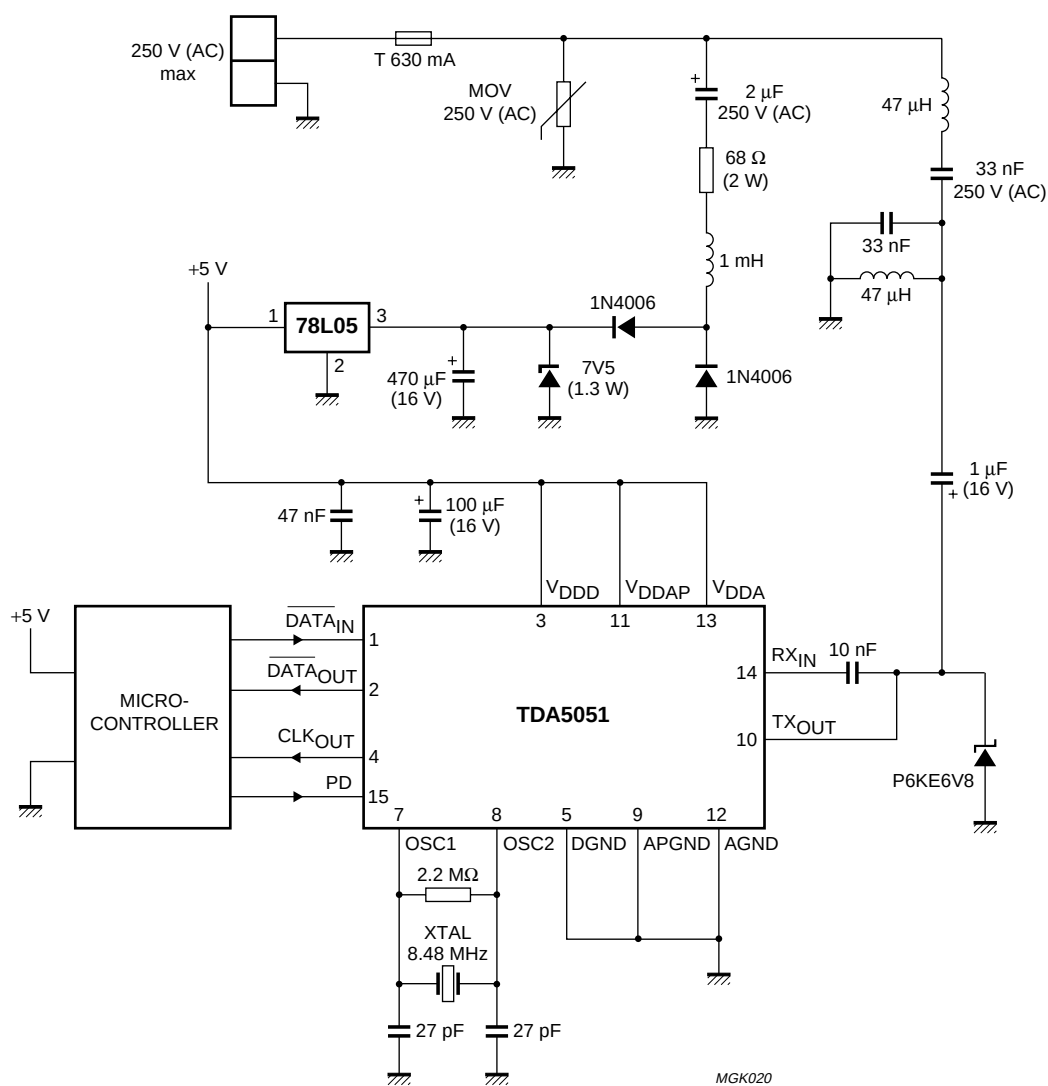
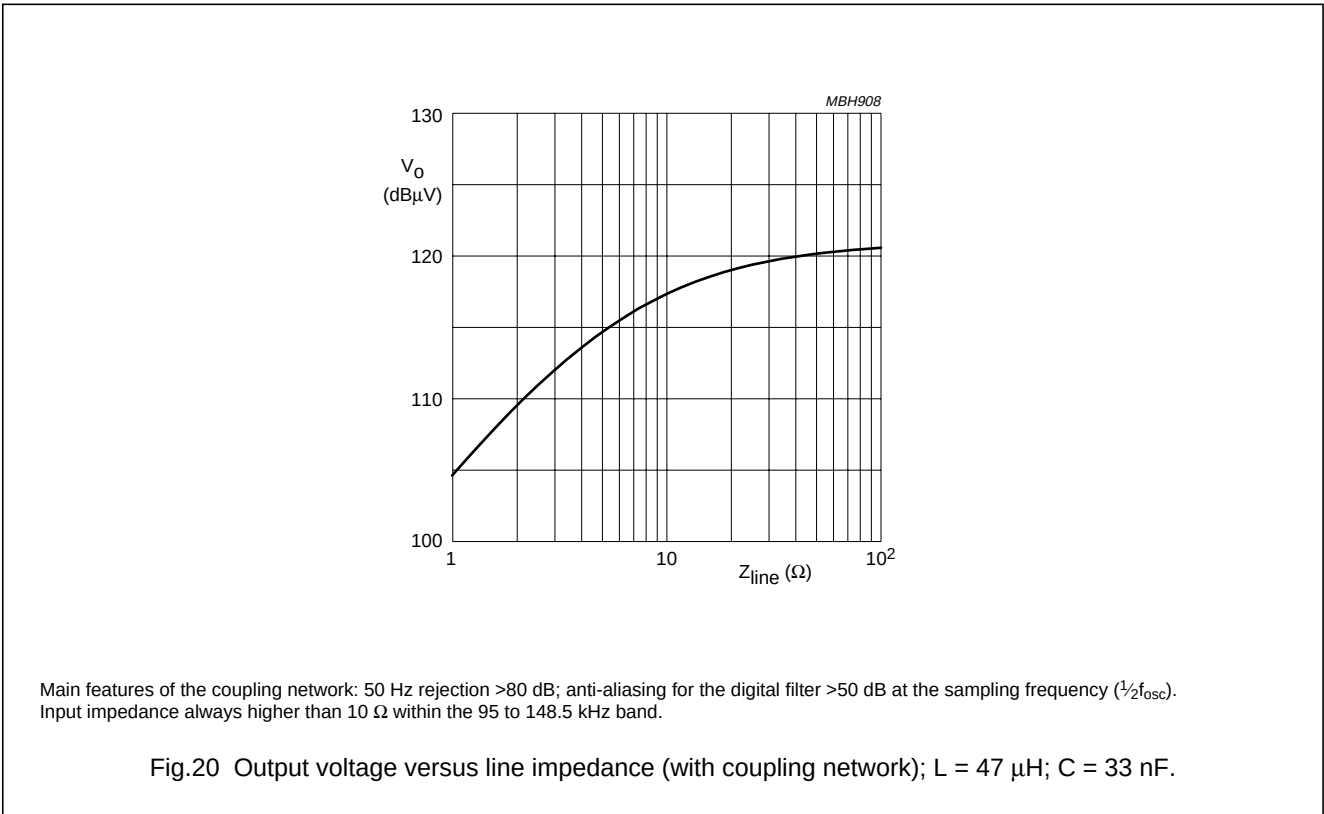
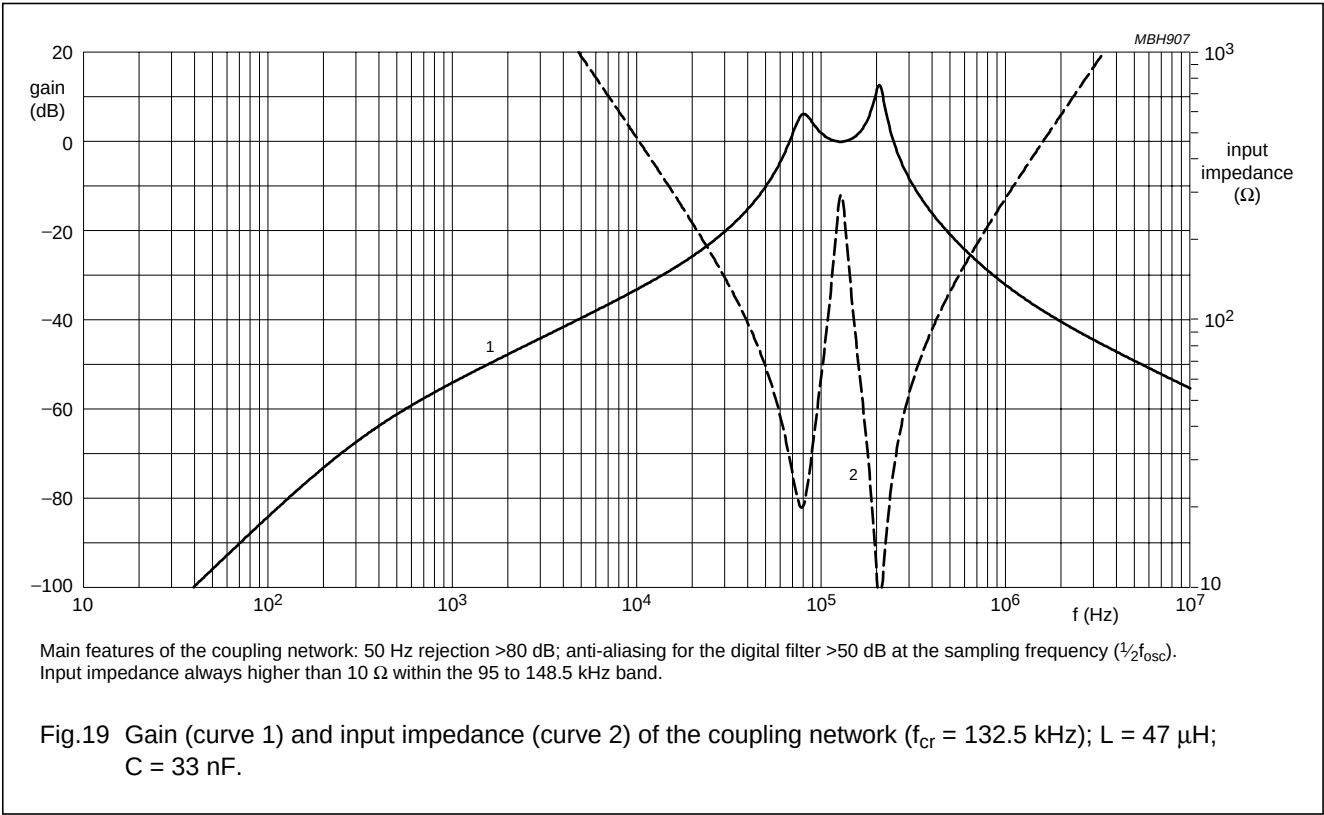


Fig.18 Application diagram without power line insulation.

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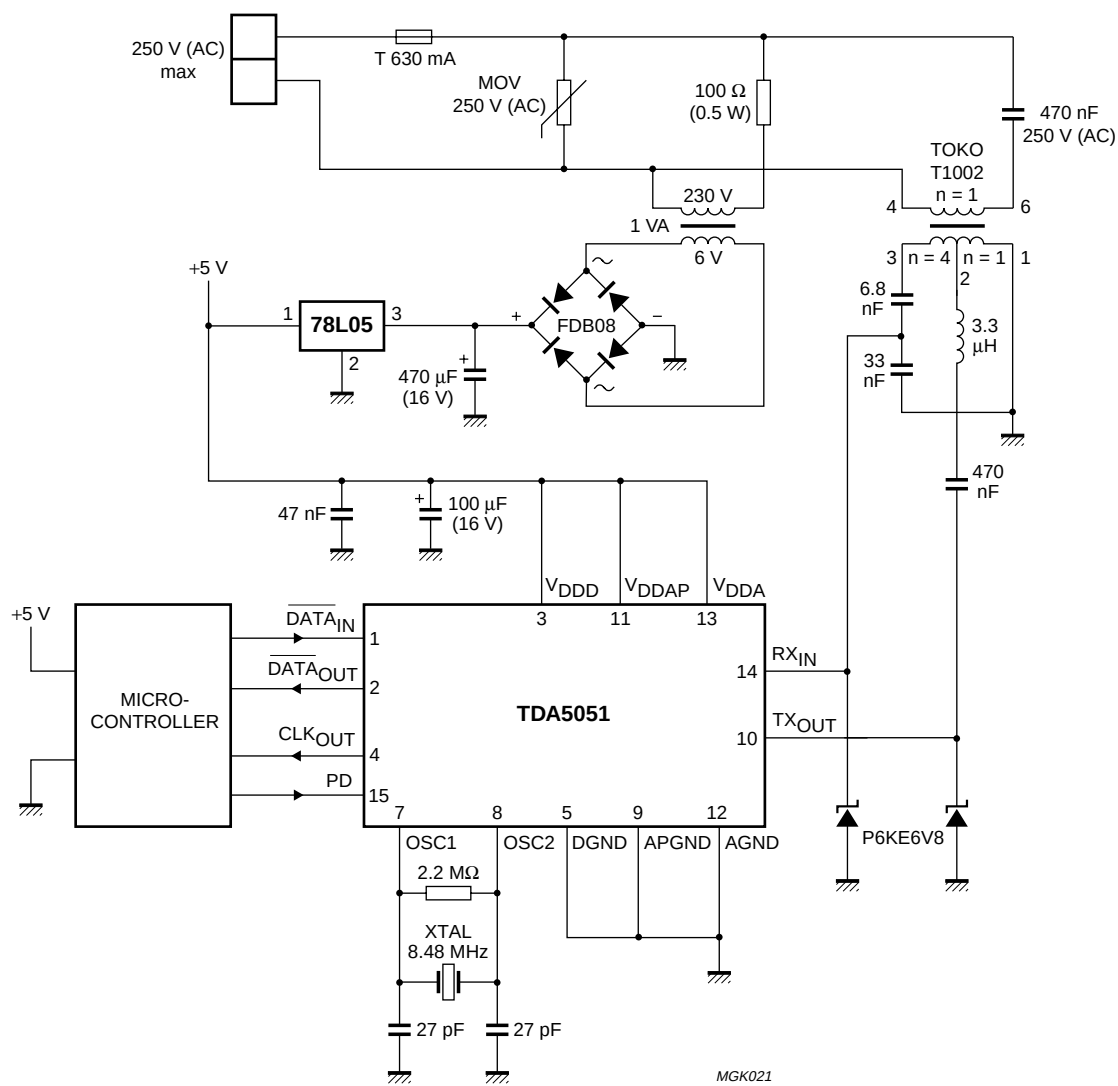


Fig.21 Application diagram with power line insulation.

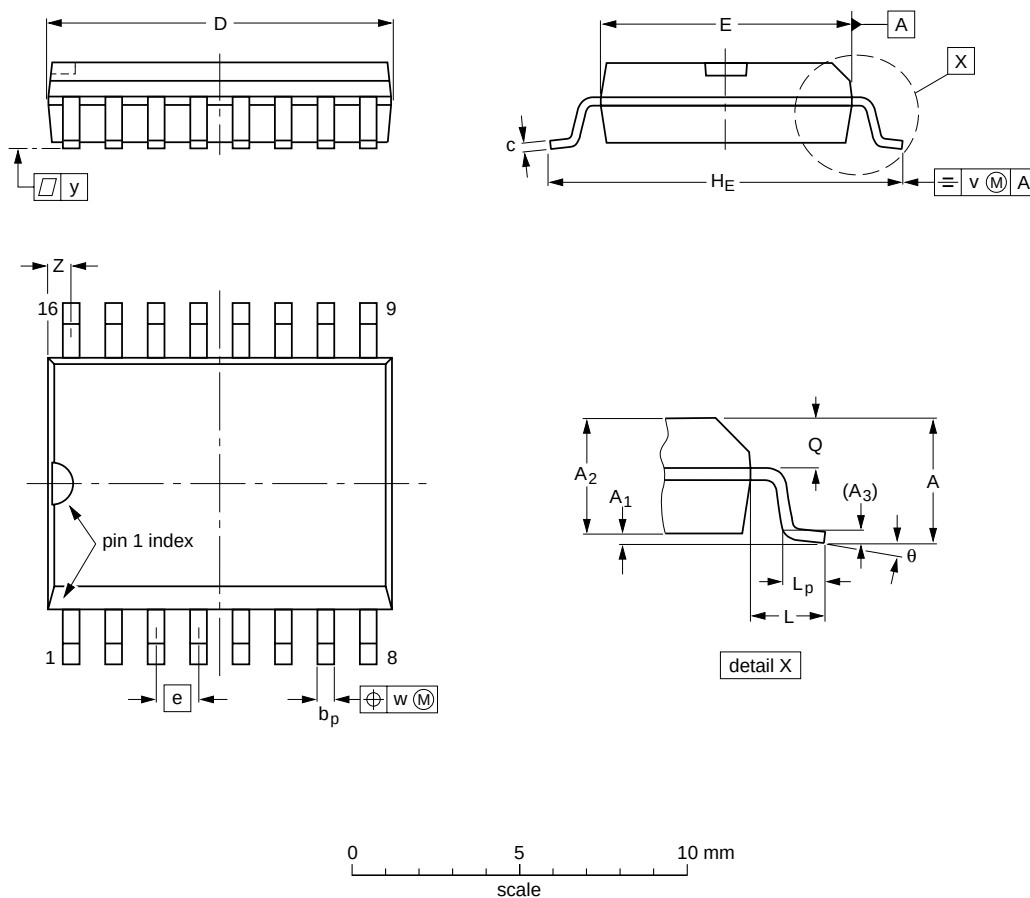
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PACKAGE OUTLINE

SO16: plastic small outline package; 16 leads; body width 7.5 mm

SOT162-1



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A _{max.}	A ₁	A ₂	A ₃	b _p	c	D ⁽¹⁾	E ⁽¹⁾	e	H _E	L	L _p	Q	v	w	y	Z ⁽¹⁾	θ
mm	2.65	0.30 0.10	2.45 2.25	0.25	0.49 0.36	0.32 0.23	10.5 10.1	7.6 7.4	1.27	10.65 10.00	1.4	1.1 0.4	1.1 1.0	0.25	0.25	0.1	0.9 0.4	8° 0'
inches	0.10	0.012 0.004	0.096 0.089	0.01	0.019 0.014	0.013 0.009	0.41 0.40	0.30 0.29	0.050	0.419 0.394	0.055	0.043 0.016	0.043 0.039	0.01	0.01	0.004	0.035 0.016	

Note

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOT162-1	075E03	MS-013AA				95-01-24 97-05-22

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SOLDERING**Introduction**

There is no soldering method that is ideal for all IC packages. Wave soldering is often preferred when through-hole and surface mounted components are mixed on one printed-circuit board. However, wave soldering is not always suitable for surface mounted ICs, or for printed-circuits with high population densities. In these situations reflow soldering is often used.

This text gives a very brief insight to a complex technology. A more in-depth account of soldering ICs can be found in our *"IC Package Databook"* (order code 9398 652 90011).

Reflow soldering

Reflow soldering techniques are suitable for all SO packages.

Reflow soldering requires solder paste (a suspension of fine solder particles, flux and binding agent) to be applied to the printed-circuit board by screen printing, stencilling or pressure-syringe dispensing before package placement.

Several techniques exist for reflowing; for example, thermal conduction by heated belt. Dwell times vary between 50 and 300 seconds depending on heating method. Typical reflow temperatures range from 215 to 250 °C.

Preheating is necessary to dry the paste and evaporate the binding agent. Preheating duration: 45 minutes at 45 °C.

Wave soldering

Wave soldering techniques can be used for all SO packages if the following conditions are observed:

- A double-wave (a turbulent wave with high upward pressure followed by a smooth laminar wave) soldering technique should be used.
- The longitudinal axis of the package footprint must be parallel to the solder flow.
- The package footprint must incorporate solder thieves at the downstream end.

During placement and before soldering, the package must be fixed with a droplet of adhesive. The adhesive can be applied by screen printing, pin transfer or syringe dispensing. The package can be soldered after the adhesive is cured.

Maximum permissible solder temperature is 260 °C, and maximum duration of package immersion in solder is 10 seconds, if cooled to less than 150 °C within 6 seconds. Typical dwell time is 4 seconds at 250 °C.

A mildly-activated flux will eliminate the need for removal of corrosive residues in most applications.

Repairing soldered joints

Fix the component by first soldering two diagonally-opposite end leads. Use only a low voltage soldering iron (less than 24 V) applied to the flat part of the lead. Contact time must be limited to 10 seconds at up to 300 °C. When using a dedicated tool, all other leads can be soldered in one operation within 2 to 5 seconds between 270 and 320 °C.

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DEFINITIONS

Data sheet status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	
Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	
Application information	
Where application information is given, it is advisory and does not form part of the specification.	

LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.

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NOTES

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